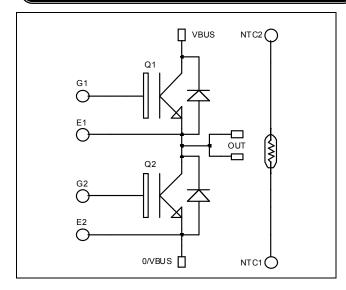
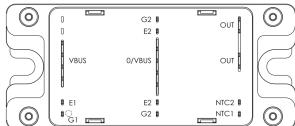


Phase leg High speed Trench + Field Stop IGBT4 Power Module







Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- High speed Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
- Kelvin emitter for easy drive
- Very low stray inductance
- Lead frames for power connections
- Internal thermistor for temperature monitoring

Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- Low profile
- RoHS Compliant

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		1200	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	170	
I_{C}	$T_{\rm C} = 80^{\circ}{\rm C}$	100	Α	
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	340	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Power Dissipation		520	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

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Electrical Characteristics (Per IGBT)

Sy	mbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
]	I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				50	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.78	2.05	2.42	V	
		$I_{\rm C} = 100A$	$T_j = 150$ °C		2.6			
V	GE(th)	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 3.8 \text{ mA}$		5.1	5.8	6.4	V
I	[_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				150	nA

Dynamic Characteristics (Per IGBT)

Symbol	Characteristic	Test Condition	ns	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			6150		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			460		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz	f = 1MHz		345		
Q_{G}	Gate charge	$V_{GE} = 15V, I_C = 100A$ $V_{CE} = 960V$			460		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Swit	tching (25°C)		30		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			57		ns
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 100A$			290		
$T_{\rm f}$	Fall Time	$R_G = 5\Omega$			16		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 100A$ $R_{G} = 5\Omega$			30		ns
$T_{\rm r}$	Rise Time				49		
$T_{d(off)}$	Turn-off Delay Time				366		
T_{f}	Fall Time				48		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 150$ °C		9.5		mJ
E_{off}	Turn off Energy	$I_{\rm C} = 100 A$ $R_{\rm G} = 5 \Omega$	$T_j = 150$ °C		5.6		111,)
R_G	Integrated gate resistor				7.5		Ω
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 600V$ $t_p \le 10\mu s$; $T_j = 150$ °C			350		A
R_{thJC}	Junction to Case Thermal Resistance					0.29	°C/W

Diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit		
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V		
I_{RM}	Reverse Leakage Current	$V_R = 1200V$				100	μΑ		
I_F	DC Forward Current		Tc = 60°C		100		A		
		$I_F = 100A$			2.4	3.5			
V_{F}		$I_F = 150A$	50A		2.7		V		
		$I_{F} = 100A$	$T_{j} = 125^{\circ}C$		1.8				
+	Reverse Recovery Time $I_F = 100A$	$T_j = 2$	$T_j = 25^{\circ}C$		385		200		
t_{rr}		$T_{j} = 125^{\circ}C$		480		ns			
0	Davarra Dagayary Chargo	$V_R = 800V$ $di/dt = 200A/\mu s$		$A: /At = 200 \text{ A} / \text{ T}_i = 25$	$T_j = 25$ °C		1.05		
Q _{rr}	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		5.24		μC		
R_{thJC}	Junction to Case Thermal Resistance					0.35	°C/W		



Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

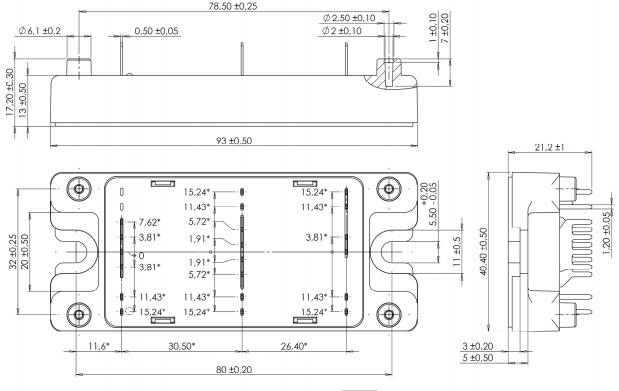
Symbol	Characteristic	Characteristic			Тур	Max	Unit
R_{25}	Resistance @ 25°C			50		kΩ	
$\Delta R_{25}/R_2$	5				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$				3952		K
$\Delta B/B$			T _C =100°C		4		%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic				Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case	4000		V		
T_{J}	Operating junction temperature range	-40	175			
T_{JOP}	Recommended junction temperature under sv	witching condit	ions	-40	T _J max -25	°C
T_{STG}	Storage Temperature Range				125	C
$T_{\rm C}$	Operating Case Temperature	-40	125			
Torque	Mounting torque	To heatsink	M5	2.5	4.7	N.m
Wt	Package Weight				160	g

Package outline (dimensions in mm)

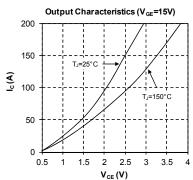


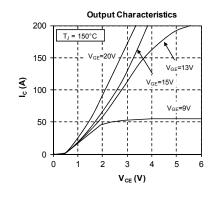
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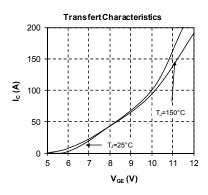
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

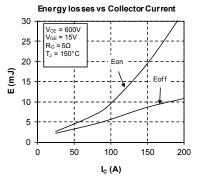


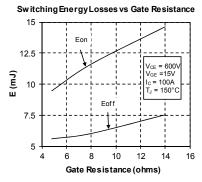
Typical performance curve

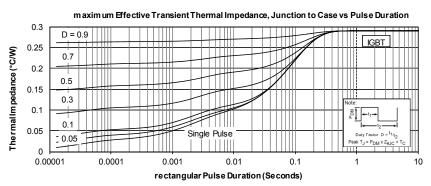






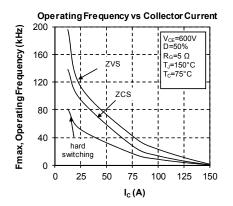


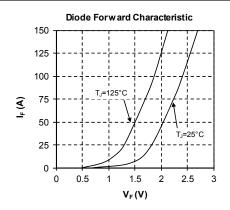




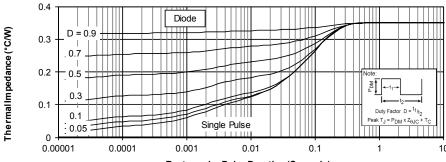


Power Matters.™





maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration



Rectangular Pulse Duration (Seconds)

5 - 6



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